

## GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 18 GHz

### Typical Applications

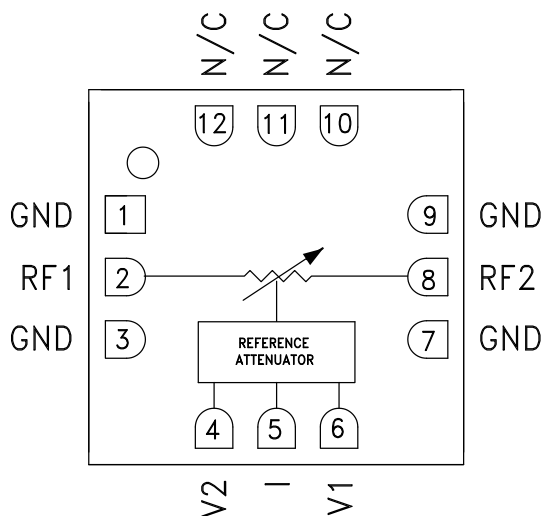
The HMC346ALC3B is ideal for:

- Test Instrumentation
- Fiber Optics & Broadband Telecom
- Microwave Radio & VSAT
- Military Radios, Radar, & ECM

### Features

- Wide Bandwidth: DC - 18 GHz
- Low Phase Shift vs. Attenuation
- 30 dB Attenuation Range
- Simplified Voltage Control
- RoHS Compliant 3 x 3 mm SMT Package

### Functional Diagram



### General Description

The HMC346ALC3B is an absorptive Voltage Variable Attenuator (VVA) in a leadless “Pb free” RoHS compliant SMT mount ceramic package operating from DC - 18 GHz. It features an on-chip reference attenuator for use with an external op-amp to provide simple single voltage attenuation control, 0 to -5V. The device is ideal in designs where an analog DC control signal must control RF signal levels over a 30 dB amplitude range. The HMC346ALC3B allows the use of surface mount manufacturing techniques.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , 50 Ohm system

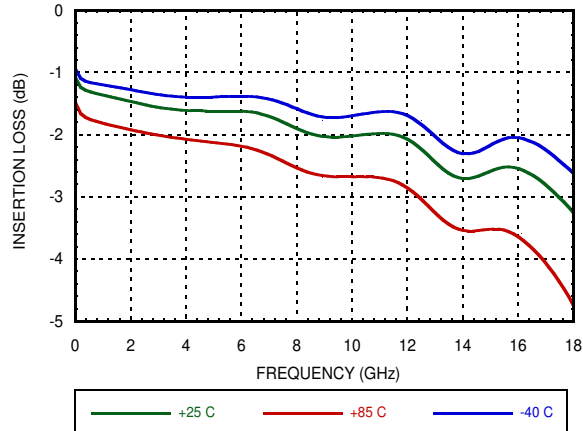
Parameter	Min	Typical	Max	Units
Insertion Loss	DC - 10 GHz	2.0	2.5	dB
	DC - 14 GHz	2.8	3.2	dB
	DC - 18 GHz	3.3	4.0	dB
Attenuation Range	DC - 12 GHz	26	30	dB
	DC - 18 GHz	20	24	dB
Return Loss	DC - 18 GHz	10		dB
Input Power for 0.25 dB Compression (0.5 - 18 GHz)	Min. Atten:	+5		dBm
	Atten. >2 dB:	+4		dBm
Input Third Order Intercept (0.5 - 18 GHz) (Two-tone Input Power = -8 dBm Each Tone)	Min. Atten:	+30		dBm
	Atten. >2 dB:	+8		dBm
Switching Characteristics	tRISE, tFALL (10/90% RF):	8		ns
	tON, tOFF (50% CTL to 10/90% RF):	16		ns

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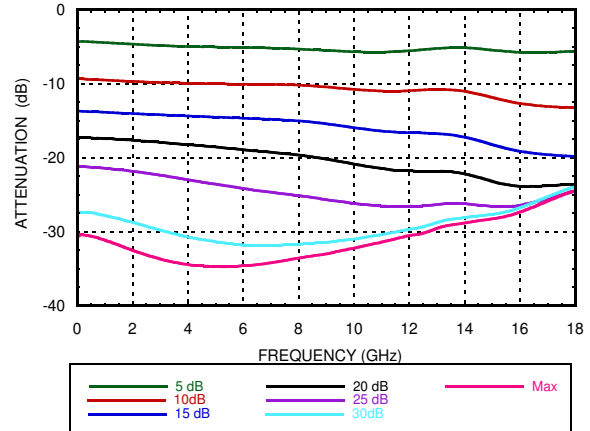
For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106  
Phone: 781-329-4700 • Order online at [www.analog.com](http://www.analog.com)  
Application Support: Phone: 1-800-ANALOG-D

**GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 18 GHz**

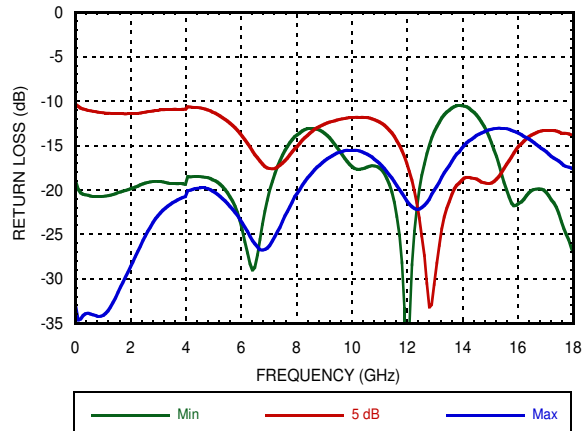
**Insertion Loss vs. Temperature**



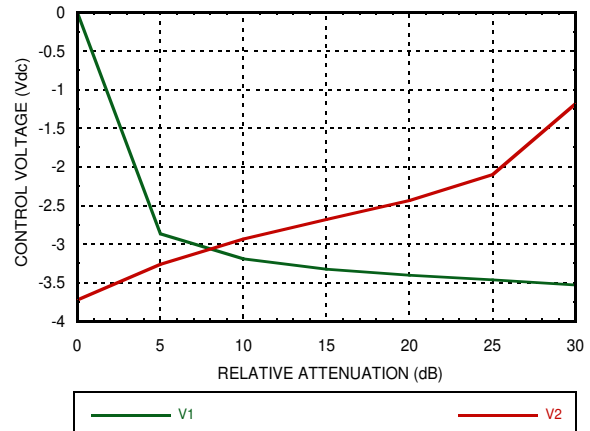
**Relative Attenuation**



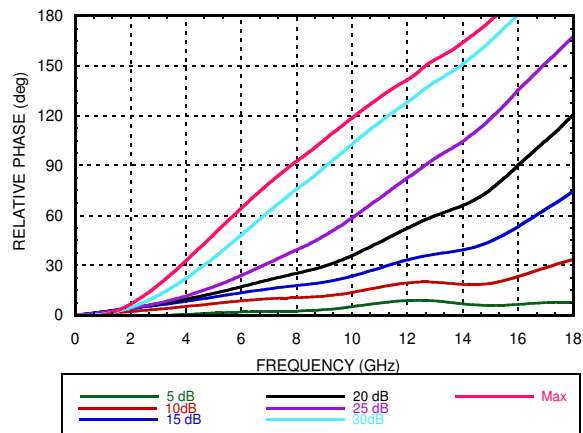
**Return Loss vs. Attenuation**



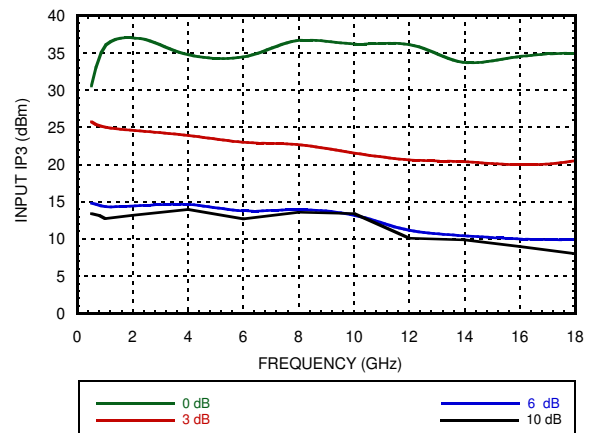
**Relative Attenuation vs. Control Voltage @ 10 GHz**



**Relative Phase vs. Attenuation**



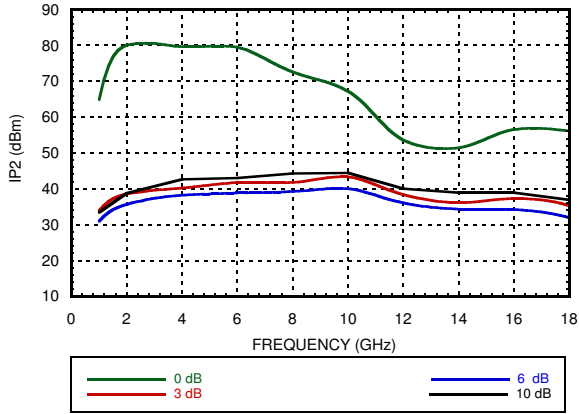
**Input IP3 vs. Attenuation\***



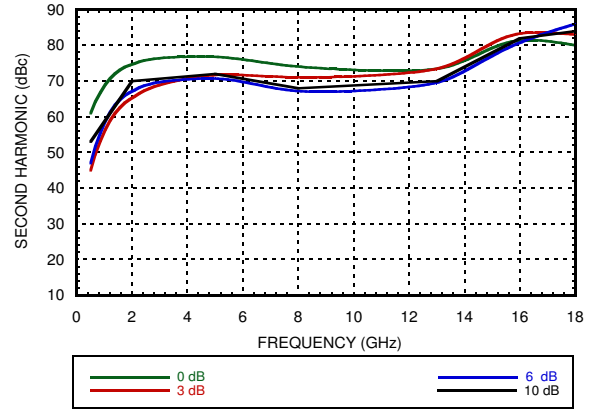
\*Two-tone input power = -8 dBm each tone, 1 MHz spacing.

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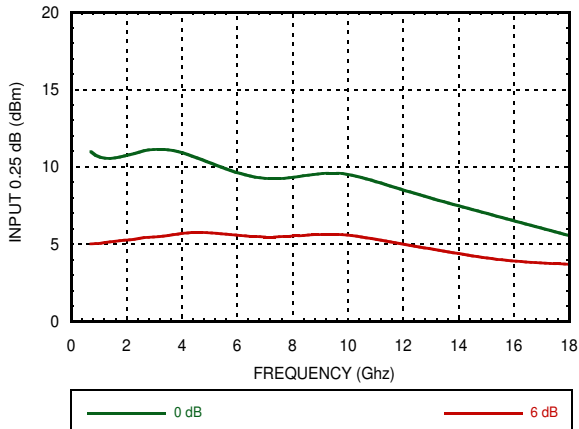
**Input IP2 vs. Attenuation\***



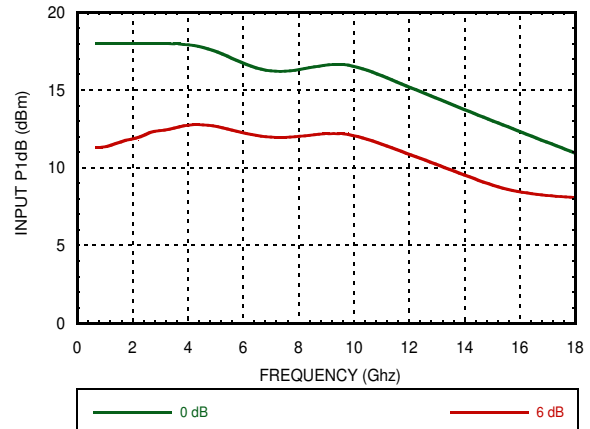
**Second Harmonic vs. Attenuation, Pin = -8 dBm**



**0.25 dB Compression vs. Attenuation**



**1 dB Compression vs. Attenuation**



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## GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 18 GHz

### Absolute Maximum Ratings

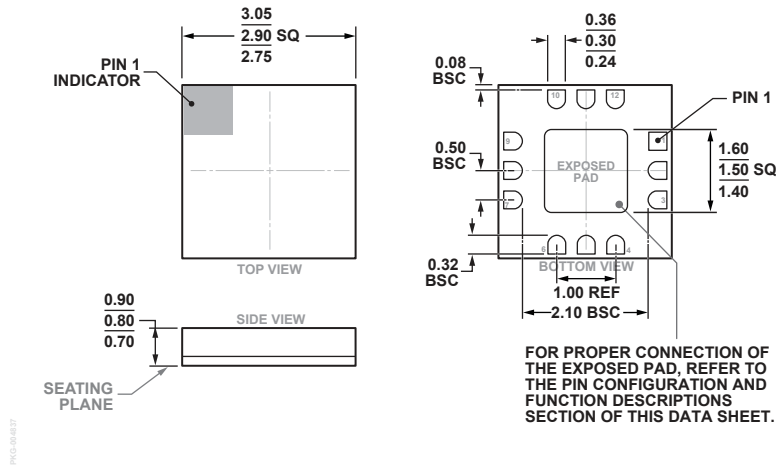
RF Input Power	+18 dBm
DC Voltage on I Pin	+/- 0.8V
Control Voltage Range	0.3 to -6V
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Junction Temperature	+175 °C
Junction to Case Thermal Resistance	10 °C/W
ESD Sensitivity (HBM)	Class 1A

State	Bias Condition
V1	-5 to 0V @ 9 mA Typical.
V2	-5 to 0V @ 9 mA Typical.



**ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS**

### Outline Drawing



12-Terminal Ceramic Leadless Chip Carrier [LLC]  
(E-12-4)  
Dimensions shown in millimeters

### Package Information


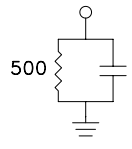

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC346ALC3B	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	346A XXXX

[[1] Max peak reflow temperature of 260 °C

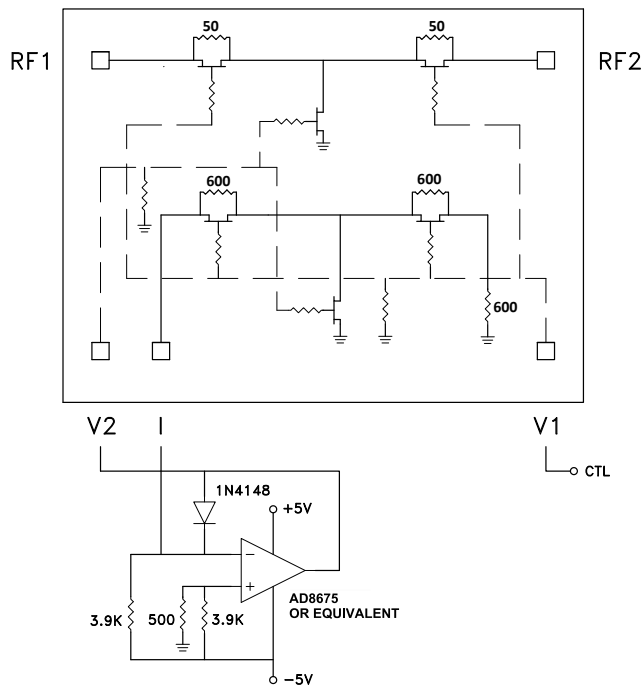
[[2] 4-Digit lot number XXXX

## GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, DC - 18 GHz

### Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	
2, 8	RF1 RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if the RF line potential is not equal to 0V.	
4, 6	V2, V1	Control input (master).	
5	I	Control input (slave).	
10, 11, 12	N/C	This pin may be connected to PCB RF/DC ground. Performance will not be affected.	

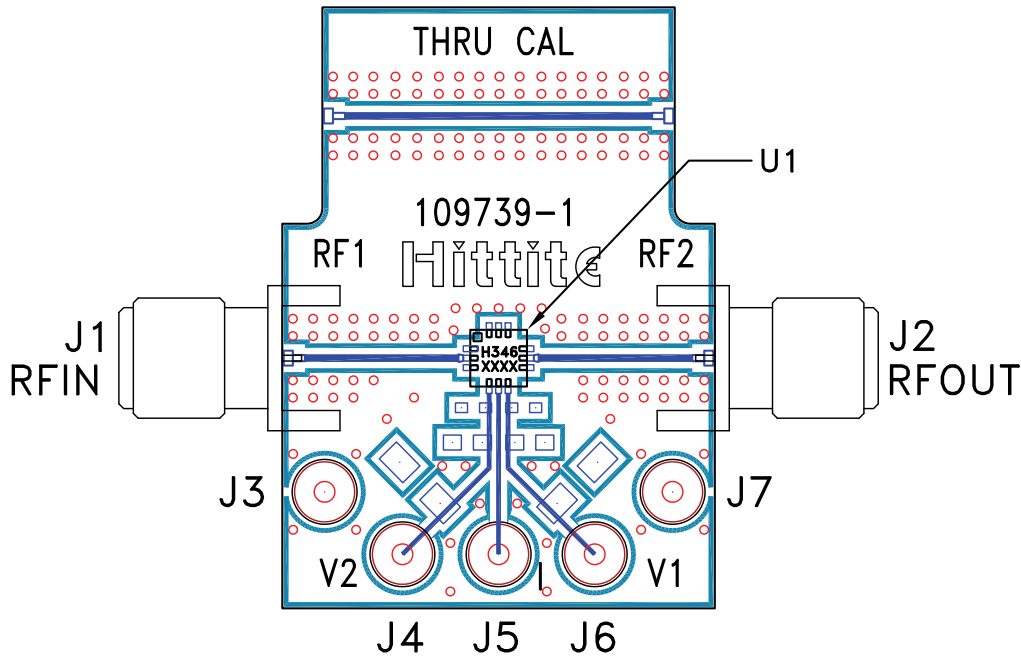
### Single-Line Control Driver



External op-amp control circuit maintains impedance match while attenuation is varied. Input control ranges from 0 Volts (min. attenuation) to -5.0 Volts (max. attenuation.)

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**Evaluation PCB**



**List of Materials for Evaluation EV1HMC346ALC3B [1]**

Item	Description
J1 - J2	PCB Mount SMA RF Connector
J3 - J7	DC Pin
U1	HMC346ALC3B VVA
PCB [2]	109739-1 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF ports should be 50 Ohm impedance and the package ground leads and package bottom should be connected directly to the PCB RF ground plane, similar to that shown above. The evaluation circuit board shown above is available from Analog Devices Inc. upon request.